

HIGH EFFICIENCY RECTIFIER

VOLTAGE RANGE: 100 --- 200 V
CURRENT: 1.5 A

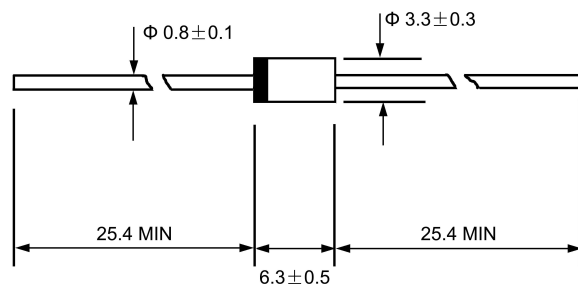
FEATURES

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with Alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

- ◇ Case: JEDEC DO--15, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL-STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.014 ounces, 0.39 grams
- ◇ Mounting position: Any

DO - 15



Dimensions in millimeters

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		ERC30 - 01	ERC30 - 02	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	100	200	V
Maximum RMS voltage	V_{RMS}	70	140	V
Maximum DC blocking voltage	V_{DC}	100	200	V
Maximum average forward rectified current 9.5mm lead length, @ $T_A = 75^\circ\text{C}$	$I_{F(AV)}$	1.5		A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @ $T_J = 125^\circ\text{C}$	I_{FSM}	60.0		A
Maximum instantaneous forward voltage @ 1.5A	V_F	0.92		V
Maximum reverse current @ $T_A = 25^\circ\text{C}$ at rated DC blocking voltage @ $T_A = 100^\circ\text{C}$	I_R	5.0 100.0		μA
Maximum reverse recovery time (Note1)	t_{rr}	100		ns
Typical junction capacitance (Note2)	C_J	50		pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	50		$^\circ\text{C/W}$
Operating junction temperature range	T_J	- 55 ---- + 150		$^\circ\text{C}$
Storage temperature range	T_{STG}	- 55 ---- + 150		$^\circ\text{C}$

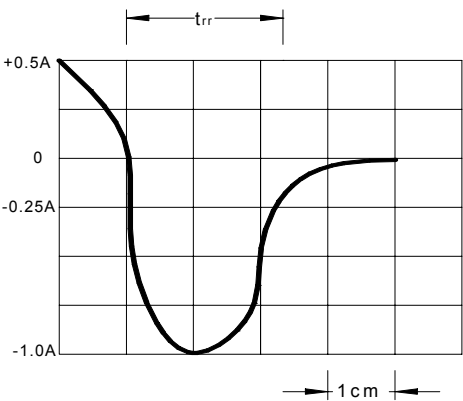
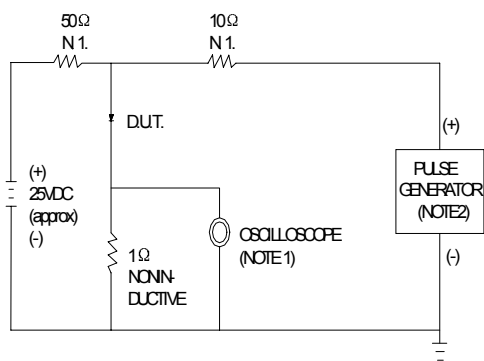
NOTE: 1. Measured with $I_F = 0.5\text{A}$, $I_R = 1\text{A}$, $t_{rr} = 0.25\text{A}$.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient.

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FIG.1 –TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC

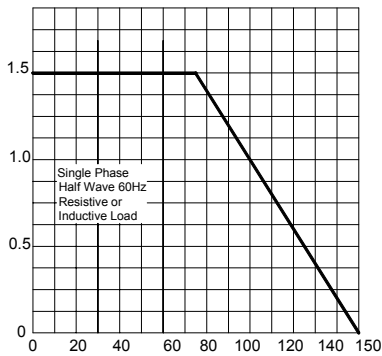


NOTES:1.RISE TIME=7ns MAX.INPUT IMPEDANCE=1MΩ.22pF
2.RISE TIME=10ns MAX.SOURCE IMPEDANCE=50Ω.

SET TIME BASE FOR 20/30 ns/cm

FIG.2 –FORWARD DERATING CURVE

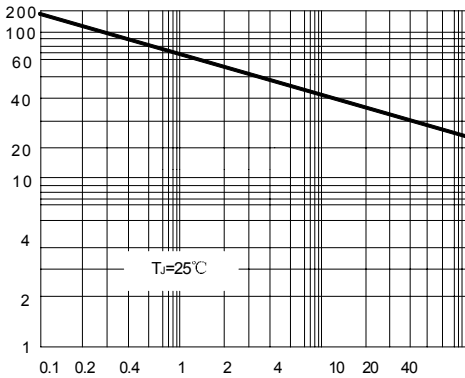
AVERAGE FORWARD RECTIFIED CURRENT.
AMPERES



AMBIENT TEMPERATURE. °C

FIG.3–TYPICAL JUNCTION CAPACITANCE

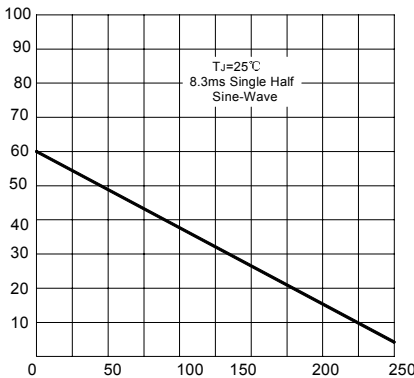
JUNCTION CAPACITANCE,pF



REVERSE VOLTAGE,VOLTS

FIG.4–PEAK FORWARD SURGE CURRENT

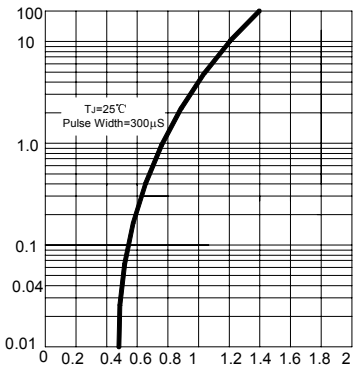
PEAK FORWARD SURGE CURRENT.
AMPERES



NUMBER OF CYCLES AT 60Hz

FIG.5 – TYPICAL FORWARD CHARACTERISTIC

INSTANTANEOUS FORWARD CURRENT
AMPERES



INSTANTANEOUS FORWARD VOLTAGE,VOLTS